

MOS FIELD EFFECT TRANSISTOR

2SK2488

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK2488 is N-Channel MOS Field Effect Transistors designed for high voltage switching applications.

FEATURES

- Low on-state resistance RDS (on) = 1.2 Ω MAX. (VGS = 10 V, ID = 5.0 A)
- Low input capacitance $C_{iss} = 2900 pF TYP.$
- High Avalanche Capability Ratings

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	900	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±30	V
Drain Current (DC)	ID (DC)	±10	Α
Drain Current (pulse)*	D (pulse)	±20	Α
Total Power Dissipation (Tc = 25 °C)	P _{T1}	150	W
Total Power Dissipation (T _A = 25 °C)	P _{T2}	3.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current**	las	10	Α
Single Avalanche Energy**	Eas	294	mJ

^{*} PW \leq 10 μ s, Duty Cycle \leq 1 %

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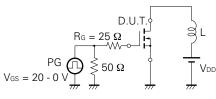
^{**} Starting T_{ch} = 25 °C, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0

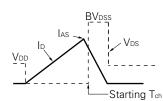


ELECTRICAL CHARACTERISTICS (TA = 25 °C)

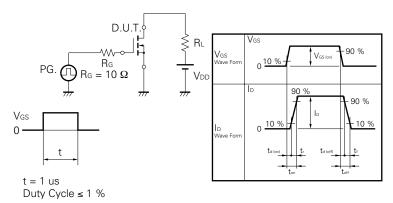
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	RDS (on)		1.0	1.2	Ω	Vgs = 10 V, ID = 5.0 A
Gate to Source Cutoff Voltage	VGS (off)	2.5		3.5	٧	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	yfs	3.5			S	V _{DS} = 20 V, I _D = 5.0 A
Drain Leakage Current	Ipss			100	μΑ	V _{DS} = V _{DSS} , V _{GS} = 0
Gate to Source Leakage Current	Igss			±100	nA	Vgs = ±30 V, Vps = 0
Input Capacitance	Ciss		2 900		pF	V _{DS} = 10 V
Output Capacitance	Coss		400		pF	V _G s = 0
Reverse Transfer Capacitance	Crss		70		pF	f = 1 MHz
Turn-On Delay Time	td (on)		35		ns	ID = 5.0 A
Rise Time	tr		30		ns	V _{GS} = 10 V
Turn-Off Delay Time	td (off)		160		ns	V _{DD} = 150 V
Fall Time	tf		32		ns	$R_G = 10 \Omega$
Total Gate Charge	Q _G		90		nC	ID = 10 A
Gate to Source Charge	Qgs		16		nC	V _{DD} = 450 V
Gate to Drain Charge	Q _{GD}		40		nC	V _G S = 10 V
Body Diode Forward Voltage	VF (S-D)		1.0		٧	IF = 10 A, VGS = 0
Reverse Recovery Time	trr		990		ns	IF = 10 A, VGS = 0
Reverse Recovery Charge	Qrr		7.0		μC	di/dt = 50 A/μs

Test Circuit 1 Avalanche Capability



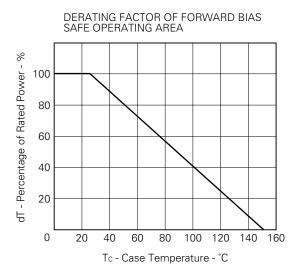


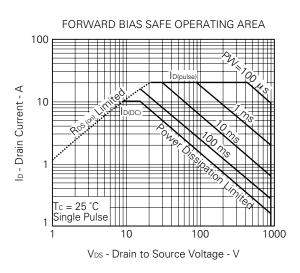
Test Circuit 2 Switching Time

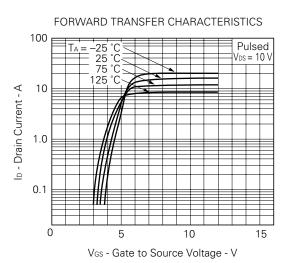


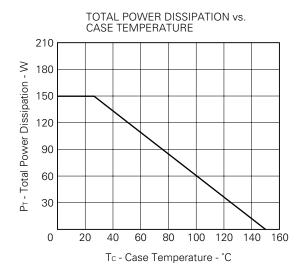
Test Circuit 3 Gate Charge

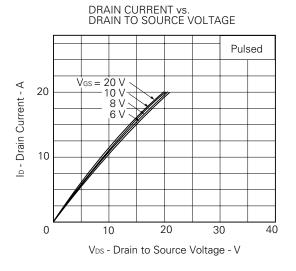
TYPICAL CHARACTERISTICS (TA = 25 °C)



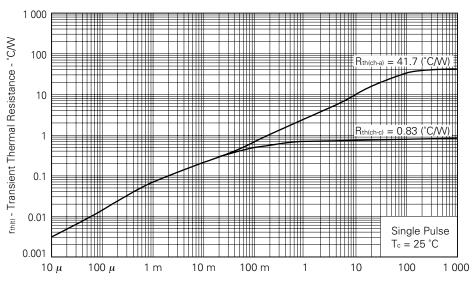






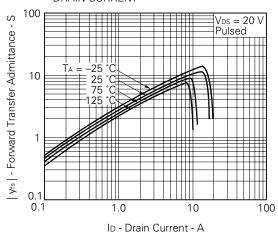


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

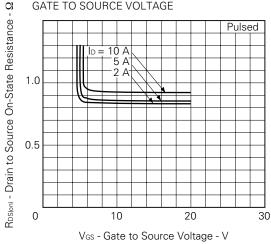


PW - Pulse Width - s

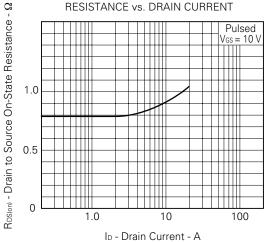




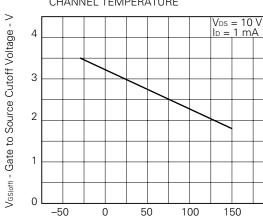
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



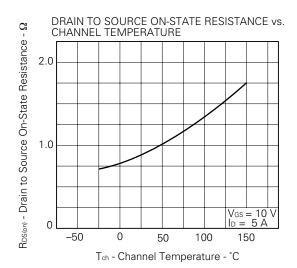
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

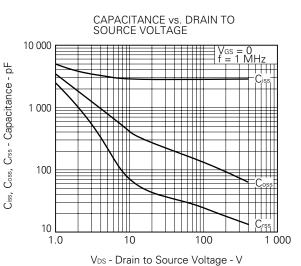


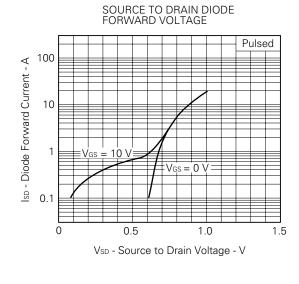
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE

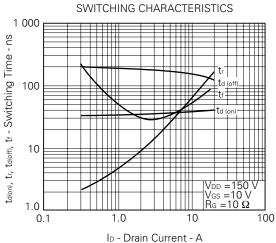


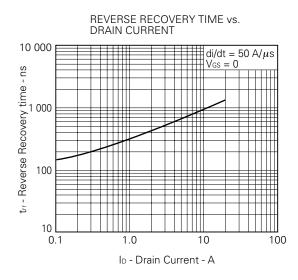
Tch - Channel Temperature - °C

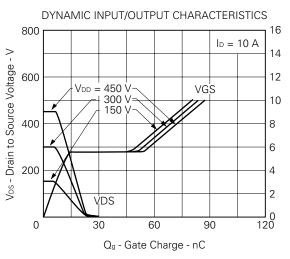


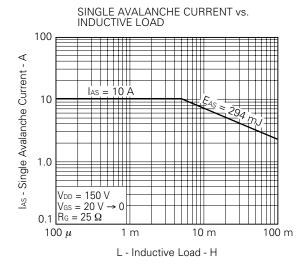


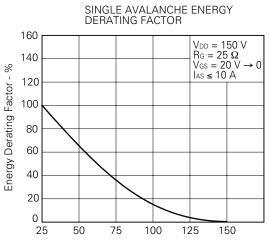








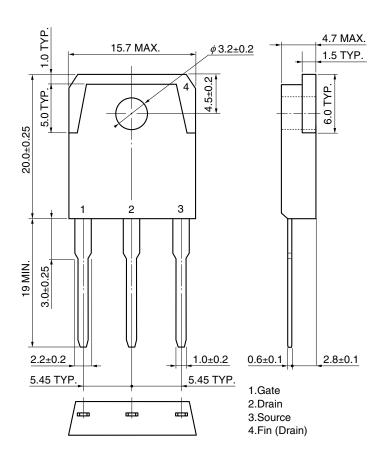




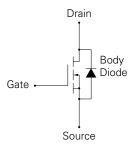
Starting T_{ch} - Starting Channel Temperature - $^{\circ}\text{C}$

PACKAGE DRAWING (Unit: mm)

<R> TO-3P (MP-88)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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